

## Pin Descriptions

Name	SO-8	SO-8EP	U-DFN3030-10	Function
SW	6, 5	6, 5	7, 6	Switch Pin. Connect inductor/freewheeling diode here, minimizing track length at this pin to reduce EMI.
GND	2	2	2, 9	GND pin
SET	1	1	1	Set Nominal Output Current Pin. Configure the output current of the device.
CTRL	8	8	10	<p>Dual function dimming control pin.</p> <ul style="list-style-type: none"> <li>Input voltage of 0.2V or lower forces the device into low current standby mode and shuts off the output.</li> <li>A PWM signal (driven by an open-drain/collector source) allows the output current to be adjusted over a wide range up to 100%.</li> <li>An analog voltage between 0.3V and 2.5V adjusts the output current between 25% and 200% of the current set by <math>0.2V/R_S</math>.</li> </ul> <p>The input impedance is about 50k<math>\Omega</math>, and if the pin is left open <math>V_{CTRL} = V_{REF}</math></p>
V <sub>IN</sub>	4	4	5	Input Supply Pin. Must be locally bypassed.
NC	3	3	3, 4, 8	No connection
EP	-	EP	EP	<p>Exposed pad: Internally connected to IC substrate.</p> <p>It should be connected to GND and as large as possible thermal mass for improved thermal impedance and power dissipation capability.</p> <p>However the exposed pad is not a Power GND return path. The dedicated GND pins must be connected to 0V. See Land Pad diagrams.</p>

## Functional Block Diagram

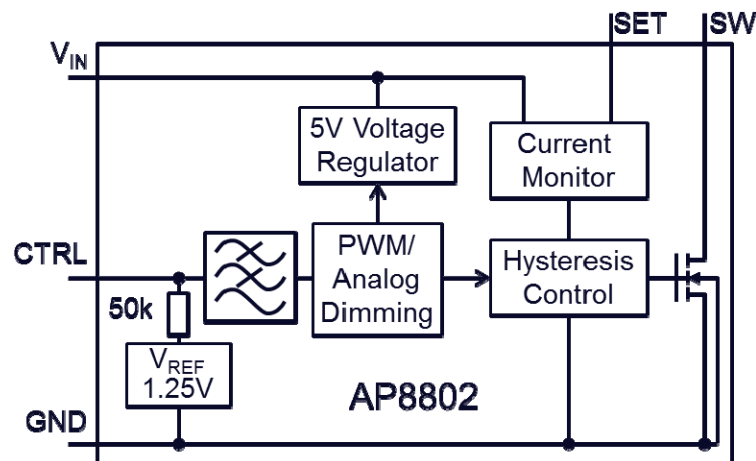


Figure. 1 Functional Block Diagram

### Absolute Maximum Ratings ( $T_A = +25^\circ\text{C}$ ) (Note 4)

Symbol	Parameter	Rating	Unit
$V_{IN}$	$V_{IN}$ pin voltage	-0.3 to +50	V
$V_{SW}$	SW voltage	-0.3 to +50	V
$V_{CTRL}$	CTRL Pin Input Voltage	-0.3 to +6	V
$V_{SENSE}$	SET Voltage (Note 5)	+0.3 to -5	V
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{LEAD}$	Lead Temperature Soldering	300	$^\circ\text{C}$
$T_{ST}$	Storage Temperature Range	-65 to +150	$^\circ\text{C}$

Note: 4 All voltages unless otherwise stated are measured with respect to GND.

5.  $V_{SENSE}$  is measured with respect to  $V_{IN}$ .

Caution: Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.  
Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices

### Recommended Operating Conditions ( $T_A = +25^\circ\text{C}$ )

Symbol	Parameter	Min	Max	Unit
$V_{IN}$	Operating input voltage relative to GND	8.0	48.0	V
$V_{CTRLDC}$	Voltage range for 24% to 200% DC dimming relative to GND (Note 6)	0.3	2.5	V
$V_{CTRL}$	Voltage low for PWM dimming relative to GND	0	0.2	V
$f_{OSC}$	Maximum switching frequency (Note 7)	—	625	kHz
$T_A$	Ambient temperature range	-40	+105	$^\circ\text{C}$
Duty Cycle	Using inductor $\geq 100\mu\text{H}$ (Note 8)	0.10	0.95	—

Notes: 6. For 100% brightness either leave floating or connect to 1.25V relative to GND.

7. AP8802 will operate at higher frequencies but accuracy will be affected due to propagation delays and also increased power dissipation will occur due to increased switching losses.

8. For most applications the LED current will be within 8% over the duty cycle range specified. Duty cycle accuracy is also dependent on propagation delay. Smaller size inductors can be used but LED current accuracy may be greater than 8% at extremes of duty cycle. This is most noticeable at low duty cycles (less than 0.1) or when the input voltage is high and only one LED is being driven.

### Electrical Characteristics ( $T_A = +25^\circ\text{C}$ , $V_{IN} = 12\text{V}$ ; unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Typ.	Max	Unit
$I_{OUT}$	Continuous switch current	(Note 9)	—	—	1	A
$I_Q$	Quiescent Current		—	75	120	$\mu\text{A}$
$V_{THD}$	Internal Threshold Voltage		184	200	216	mV
$V_{SENSEHYS}$	Sense threshold hysteresis		—	15	—	%
SET	SET pin input current	$V_{SET} = V_{IN} - 0.2$	—	5	—	$\mu\text{A}$
$V_{REF}$	Internal Reference Voltage		—	1.25	—	V
$R_{DS(ON)}$	On Resistance of MOSFET	$I_{SW} = 0.8\text{A}$	—	0.65	1.10	$\Omega$
$I_{SW\_LEAKAGE}$	Switch leakage current		—	—	8	$\mu\text{A}$
$\theta_{JA}$	Thermal Resistance Junction-to-Ambient	SO-8 (Note 10)	—	82	—	$^\circ\text{C/W}$
		SO-8EP (Note 10)	—	45	—	$^\circ\text{C/W}$
		U-DFN3030-10 (Note 10)	—	38	—	$^\circ\text{C/W}$
$\theta_{JC}$	Thermal Resistance Junction-to-Case	SO-8 (Note 10)	—	52	—	$^\circ\text{C/W}$
		SO-8EP (Note 10)	—	7	—	$^\circ\text{C/W}$
		U-DFN3030-10 (Note 10)	—	24	—	$^\circ\text{C/W}$

Notes: 9. Refer to figure 8 for the device derating curve.  
 10. Test condition for SO-8, SO-8EP and U-DFN3030-10: Device mounted on FR-4 PCB, 2"x2", 2oz copper, minimum recommended pad layout on top layer and thermal vias to bottom layer ground plane. For better thermal performance, larger copper pad for heat-sink is needed.

## Typical Characteristics

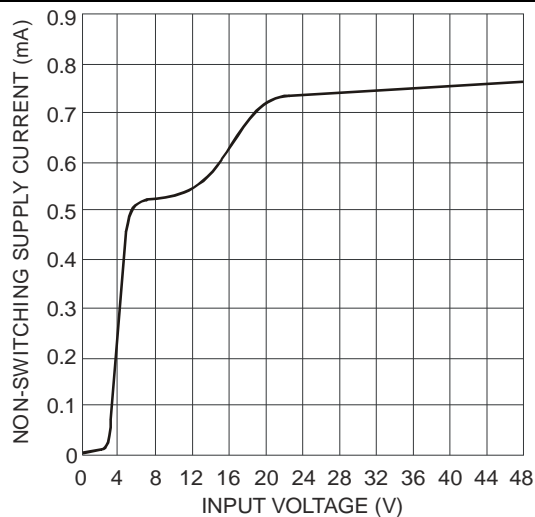


Figure 2 Supply Current (not switching) vs. Input Voltage

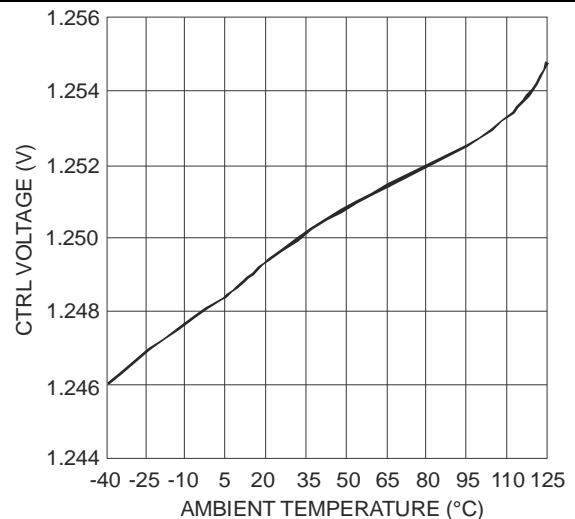


Figure 3  $V_{CTRL}$  vs. Ambient Temperature

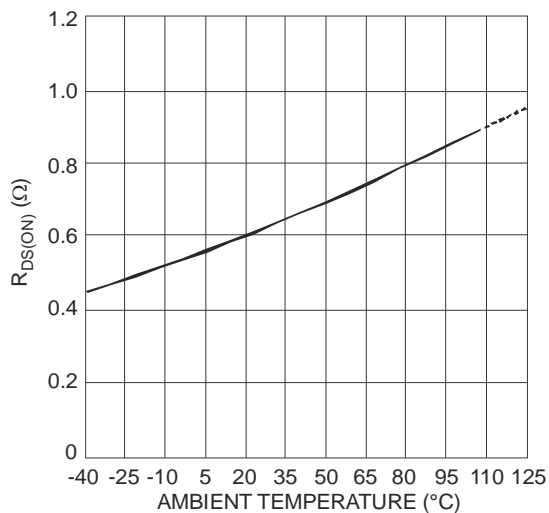


Figure 4  $R_{DS(ON)}$  vs. Ambient Temperature

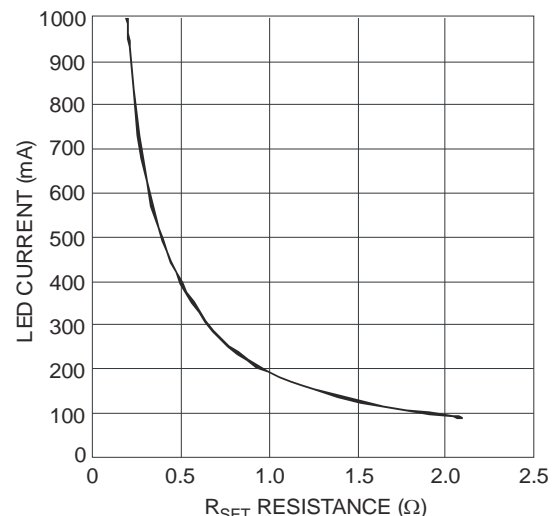


Figure 5 LED Current vs.  $R_{SET}$

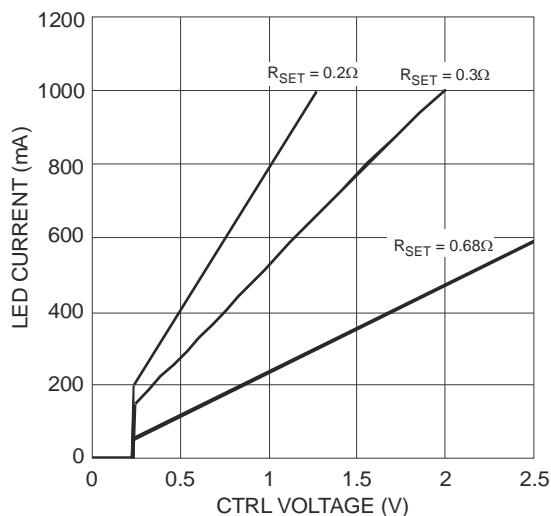


Figure 6 LED Current vs.  $V_{CTRL}$

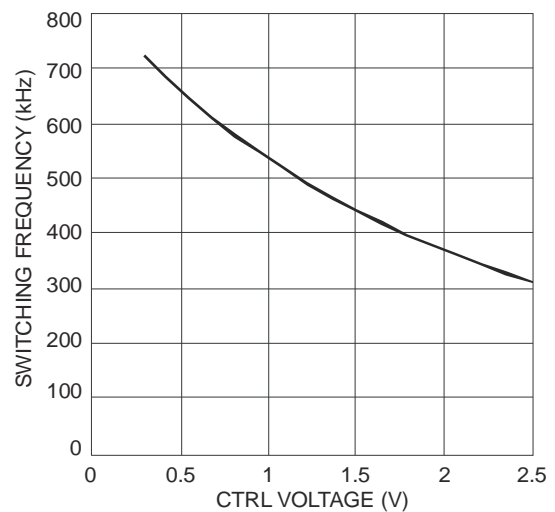
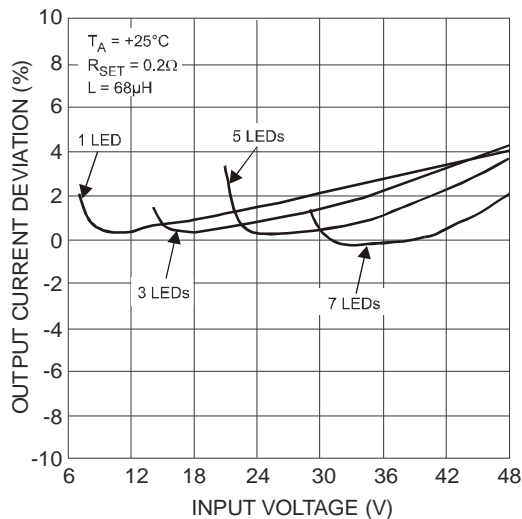
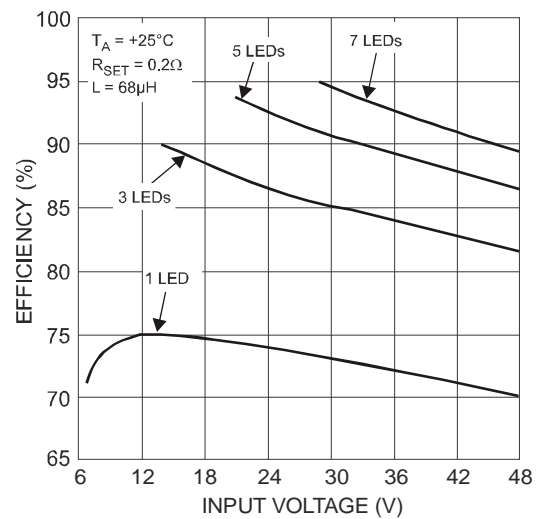


Figure 7 Switching Frequency vs.  $V_{CTRL}$

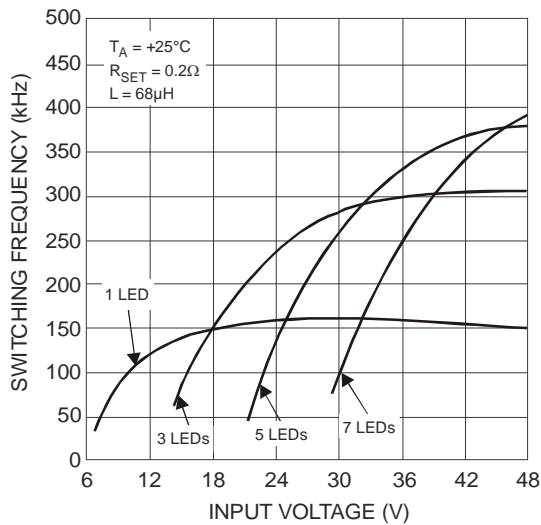
**Typical Characteristics** ( $T_A = +25^\circ\text{C}$ ,  $V_{IN} = 40\text{V}$ ,  $L = 68\mu\text{H}$ ; unless otherwise stated.)



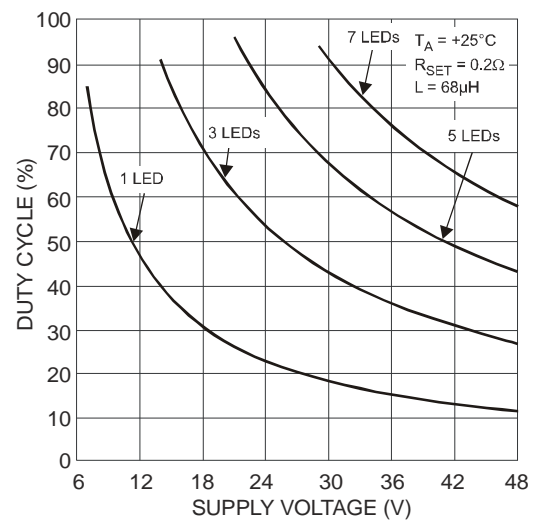
**Figure 8 LED Current vs. Input Voltage**



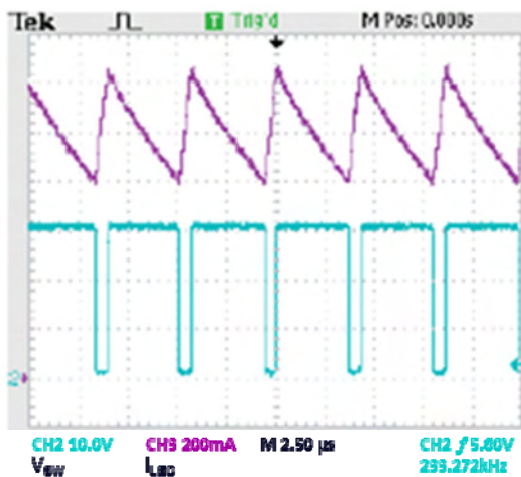
**Figure 9 Efficiency vs. Input Voltage**



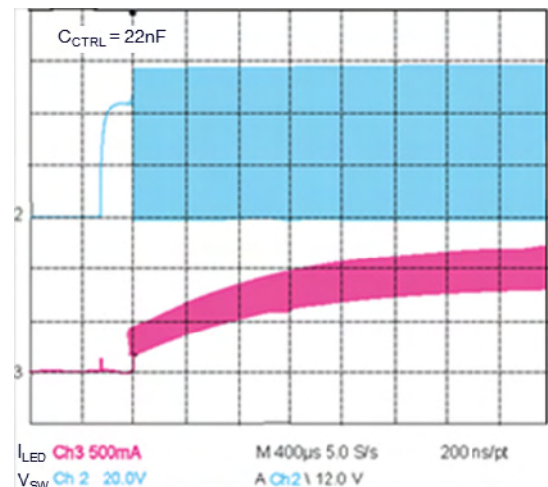
**Figure 10 Switching Frequency vs. Input Voltage**



**Figure 11 Duty Cycle vs. Input Voltage**



**Fig. 12 Steady State Waveforms**



**Fig.13 Start-Up Showing LED Current Soft Start**

## Application Information

### LED Current Control

The LED current is controlled by the resistor  $R_{SET}$  in Figure 14 connected between  $V_{IN}$  and SET. The nominal average output current in the LED(s) with the CTRL pin open circuit is defined as:

$$I_{LED} = \frac{V_{THD}}{R_{SET}}$$

where  $V_{THD}$  is the voltage between the  $V_{IN}$  and SET pins and is nominally 200mV.

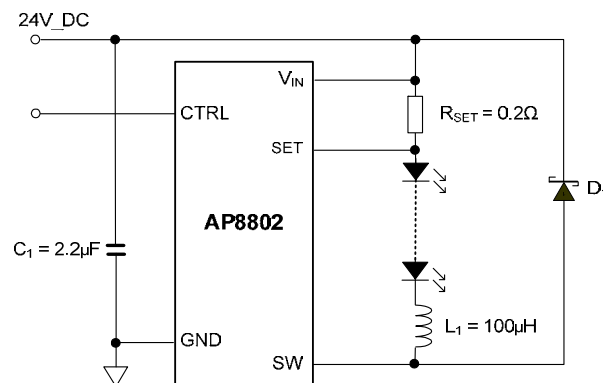


Figure. 14 Typical Application Circuit for  $I_{LED} = 1A$

### Inductor Selection

This section highlights how to select the inductor suitable for the application requirements in terms of switching frequency, LED current accuracy and temperature.

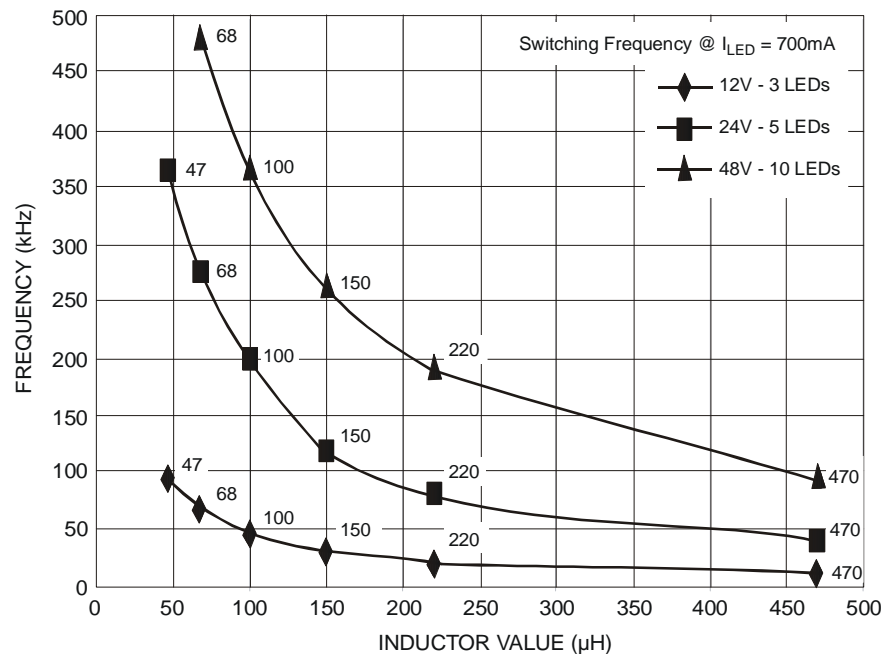
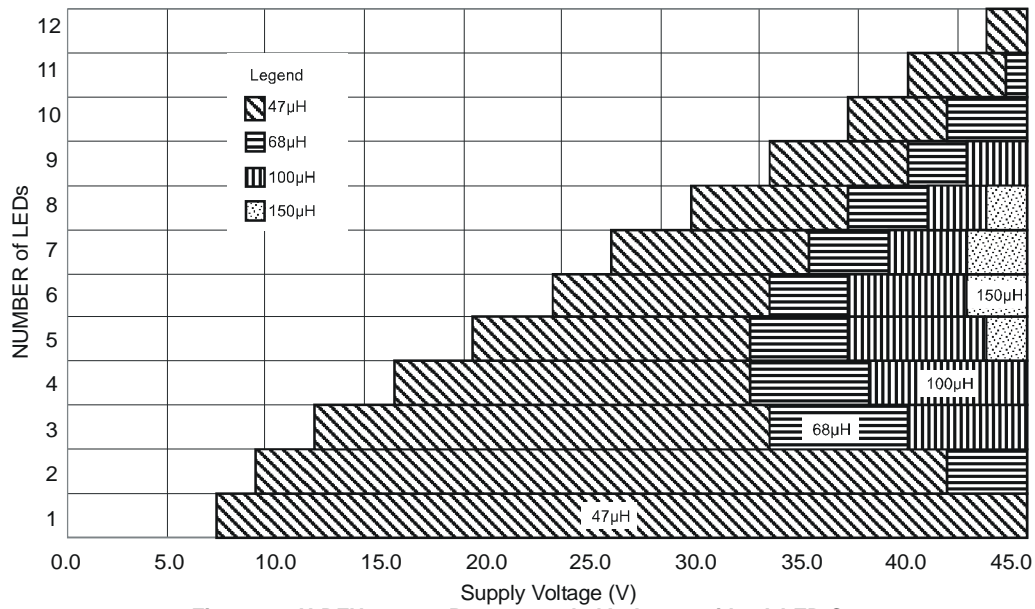


Figure. 15 Switching Frequency vs. Inductor Value

The inductor influences the LED current accuracy that the system is able to provide. The following section highlights how to select the inductor in relation to the device packages and the LED current, while maintaining the chip temperature below 70°C.

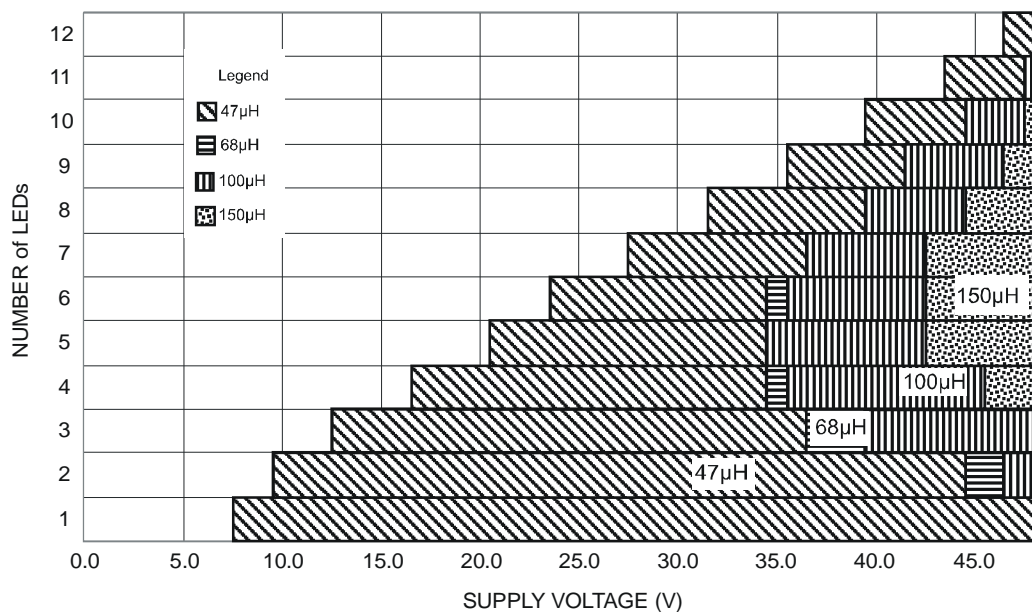
**Application Information (cont.)**

**AP8802 U-DFN3030-10 Minimum Recommended Inductor - LED Current 1A**  
8% Accuracy, <70°C Case Temperature



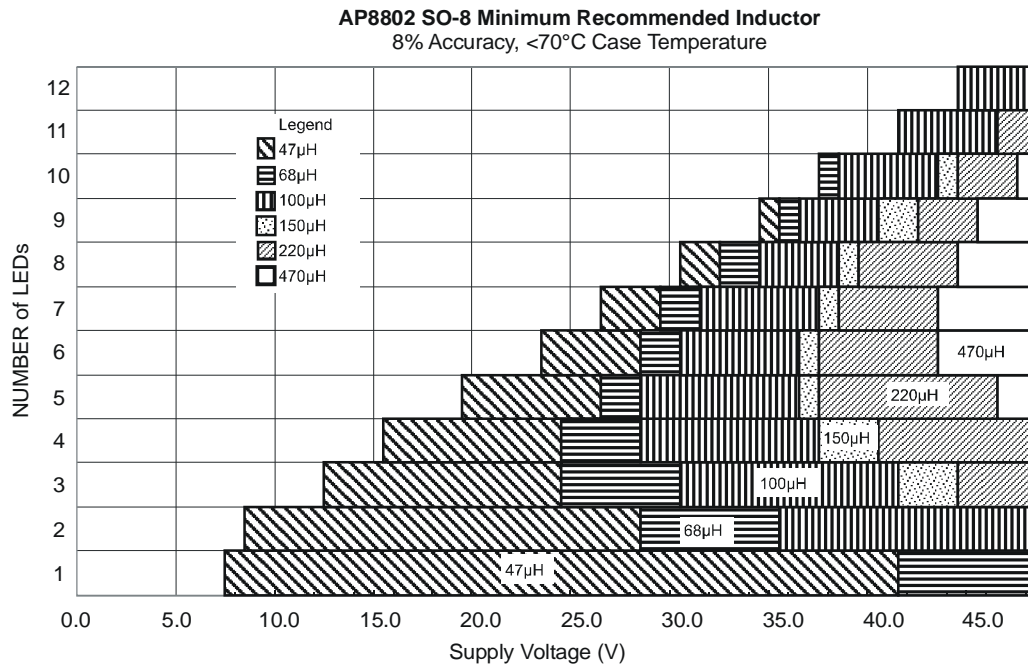
**Figure 16 U-DFN3030-10 Recommended Inductor with 1A LED Current**

**AP8802 SO-8EP Minimum Recommended Inductor**  
8% Accuracy, <70°C Case Temperature, 1A Target Current



**Figure 17 SO-8EP Recommended Inductor with 1A LED Current**

## Application Information (cont.)



**Figure 18 SO-8 Recommended Inductor with 700mA LED Current**

### Capacitor Selection

The small size of ceramic capacitors makes them ideal for AP8802 applications. X5R and X7R types are recommended because they retain their capacitance over wider voltage and temperature ranges than other types such as Z5U. A 2.2μF input capacitor is sufficient for most intended applications of AP8802.

A 4.7μF input capacitor is suggested for application with an input voltage equal or higher than 40V.

### Diode Selection

Schottky diodes, e.g. B2100 or B1100, with their low forward voltage drop and fast reverse recovery, are the ideal choice for AP8802 applications.



## Application Information (cont.)

### LED Current Adjustment/Dimming

The LED current for the AP8802 can be adjusted by driving the CTRL with a digital signal (PWM dimming) or by driving the CTRL with a DC voltage between 0.3V and 2.5V (dc dimming).

If the CTRL pin is driven by an external voltage (lower than 2.5V), the average LED current is:

$$I_{LED} = \frac{V_{CTRL}}{V_{REF}} \times \frac{V_{THD}}{R_{SET}} \quad \text{where } V_{REF} \text{ is nominally } 1.25V$$

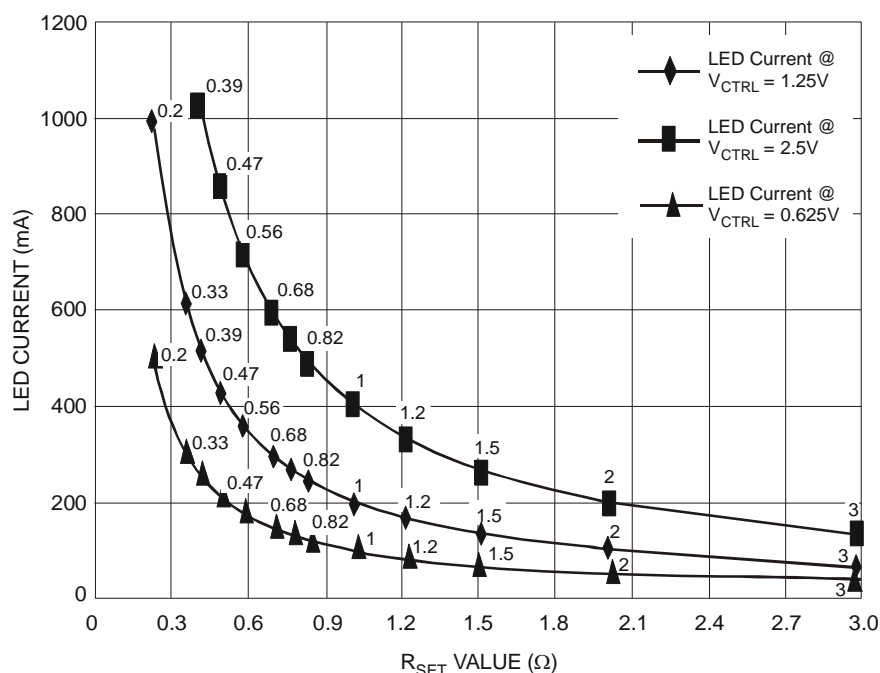


Figure 19 LED Current Setting vs. R<sub>SET</sub> and V<sub>CTRL</sub>

Figure 19 shows that reducing the CTRL voltage by a factor of 2 also reduces the LED current by a factor of 2. The AP8802 has the ability vary the LED current by a factor of 2 above the default value set by R<sub>SET</sub> down to a factor of 0.24 of the nominal LED current. This provides an 8.33:1 dynamic range of the dc dimming.

A low pass filter on the CTRL pin of the AP8802 automatically provides some soft-start function of the LED current on initial start-up (this phenomenon can be seen in figure 7); the built in soft-start period can be increased by the addition of an external capacitor onto the CTRL pin.

The AP8802's dimming range can be increased above this DC dimming factor by applying a PWM signal to the CTRL pin using this method dimming dynamic ranges above 100 can be achieved.

## Application Information (cont.)

### PWM Dimming of LED Current

When a low frequency PWM signal with voltages between 2.5V and a low level of zero is applied to the CTRL pin the output current will be switched on and off at the PWM frequency. The resultant LED current  $I_{LEDavg}$  will be proportional to the PWM duty cycle. See Figure 20.

A Pulse Width Modulated (PWM) signal with a max resolution of 8-bit, can be applied to the CTRL pin to change the output current to a value above or below the nominal average value set by resistor  $R_{SET}$ .

To achieve this resolution the PWM frequency has to be lower than 500Hz. The ultimate resolution will be determined by the number of switching cycles required to get back to nominal LED current once the PWM voltage is high relative to PWM frequency. Lower switching frequencies and higher PWM frequencies will result in lower PWM dimming dynamic ranges.

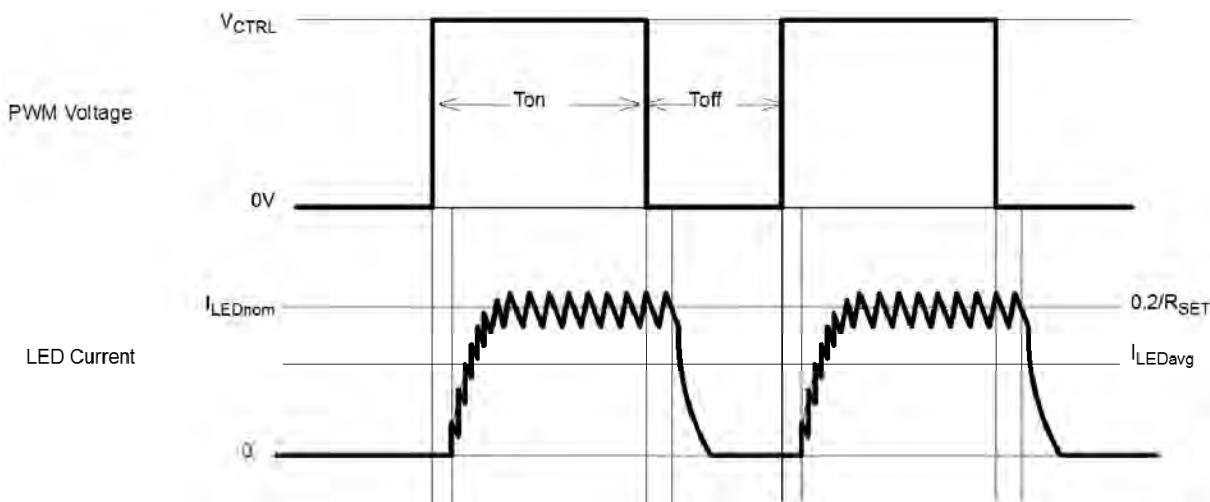


Figure 20. Low Frequency PWM Operating Waveforms

There are different ways of accomplishing PWM dimming of the AP8802 LED current:

#### Directly Driving CTRL Input

A Pulse Width Modulated (PWM) signal with duty cycle  $DPWM$  can be applied to the CTRL pin to adjust the output current to a value above or below the nominal average value set by resistor  $R_{SET}$ . When driving the CTRL with a voltage waveform care should be taken not to exceed a drive voltage of 2.5V (where extra brightness is required) or 1.25V if a maximum of 100% brightness is required.

A way of avoiding over-driving the CTRL pin is use an open collector/drain driver to drive the CTRL pin.

#### Driving the CTRL Input via Open Collector Transistor

The recommended method of driving the CTRL pin and controlling the amplitude of the PWM waveform is to use a small NPN switching transistor. This uses the internal pull-up resistor between the CTRL pin and the internal voltage reference to pull-up CTRL pin when the external transistor is turned off.

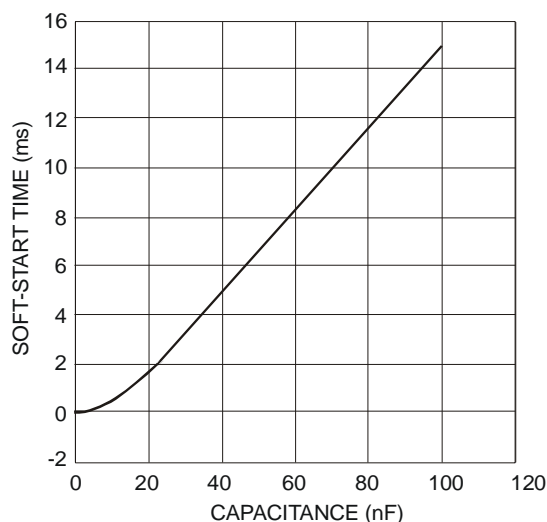
#### Driving the CTRL Input From a Microcontroller

If the CTRL pin is driven by a MOSFET (either discrete or open-drain output of a micro-controller) then Schottky diode maybe be required due to high Gate / Drain capacitance, which could inject a negative spike into CTRL input of the AP8802 and cause erratic operation but the addition of a Schottky clamp diode (eg Diodes Inc. SD103CWS) to ground and inclusion of a series resistor (3.3k) will prevent this.

## Application Information (cont.)

### Soft-Start

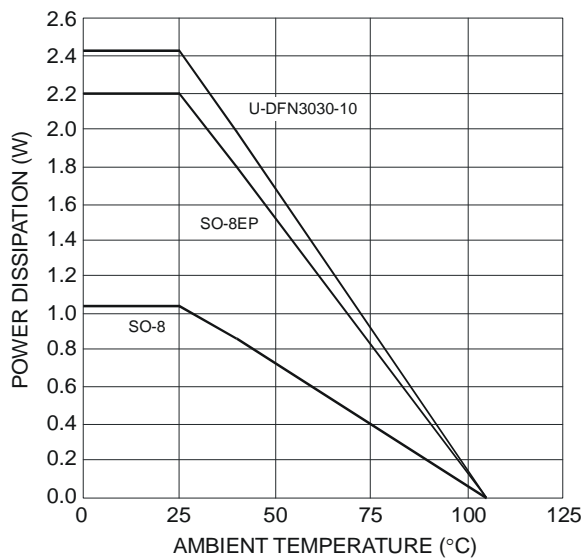
An external capacitor from the CTRL pin to ground will provide a soft-start delay, by increasing the time taken for the voltage on this pin to rise to the turn-on threshold and by slowing down the rate of rise of the control voltage at the input of the comparator. Adding capacitance increases this delay by approximately 200 $\mu$ s/nF. The graph below shows the variation of soft-start time for different values of capacitor.



**Figure. 21 Soft-Start Time vs. Capacitance from ADJ Pin to Ground**

### Thermal Considerations

The graph below in Figure 22, gives details for power derating. This assumes the device to be mounted on a 25x25mm PCB with 1oz copper standing in still air.



**Figure. 22 AP8802 Derating Curves**

## Application Information (cont.)

### Package Selection

The device comes with a wide selection of packages. The suggested package is able to provide a case temperature below 70°C (with an ambient temperature of +25°C) for the combination of input voltage and load requested.

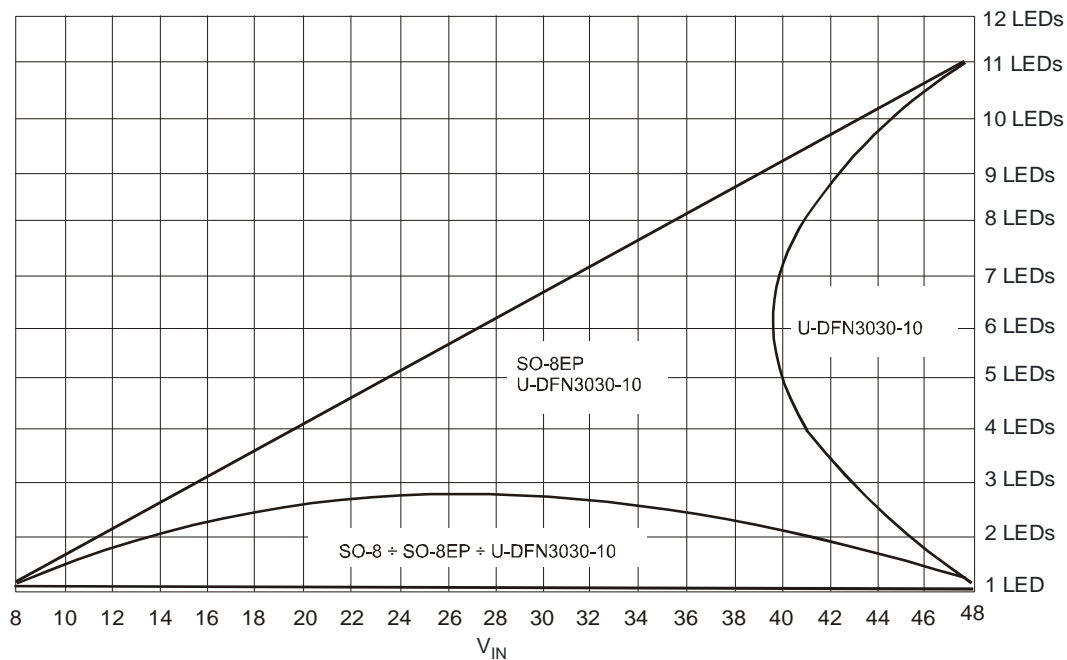


Figure. 22 Suggested Package @  $I_{LED} = 1A$  and 100µH Inductor

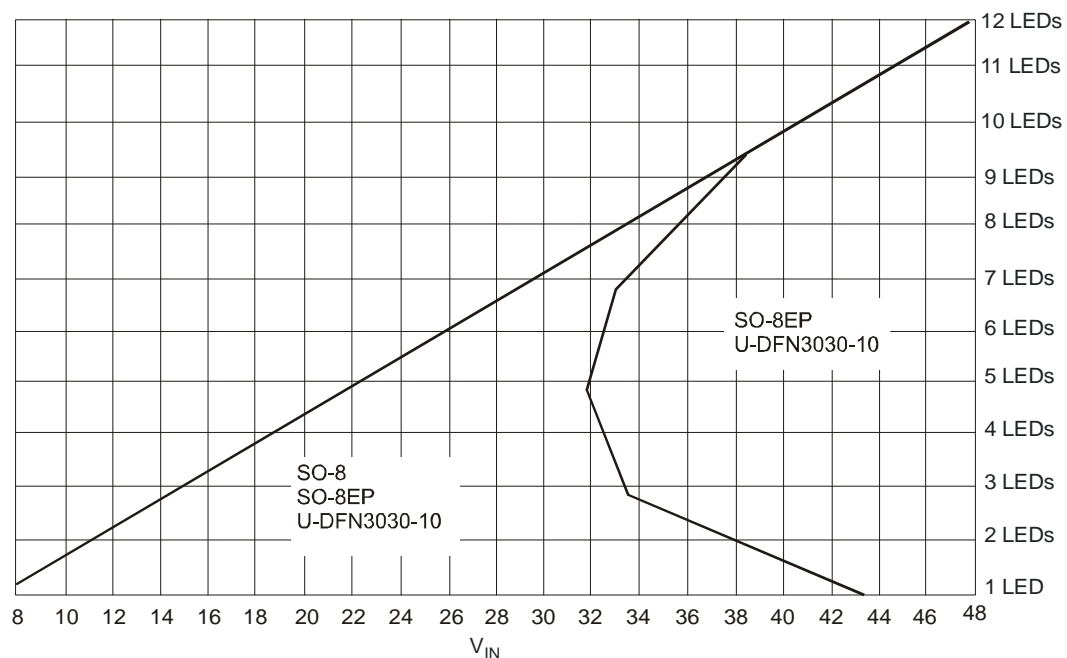


Figure. 23 Suggested Package @  $I_{LED} = 700mA$  and 100µH Inductor

## Applications Information (cont.)

### Fault Condition Operation

The AP8802 has by default open LED protection. If the LEDs should become open circuit the AP8802 will stop oscillating; the SET pin will rise to  $V_{IN}$  and the SW pin will then fall to GND. No excessive voltages will be seen by the AP8802.

If the LEDs should become shorted together the AP8802 will continue to switch however the duty cycle at which it will operate will change dramatically and the switching frequency will most likely decrease. The on-time of the internal power MOSFET switch will be significantly reduced because almost all of the input voltage is now developed across the inductor. The off-time will be significantly increased because the reverse voltage across the inductor is now just the Schottky diode voltage (See Figure 20) causing a much slower decay in inductor current. During this condition the inductor current will remain within its controlled levels and so no excessive heat will be generated within the AP8802.

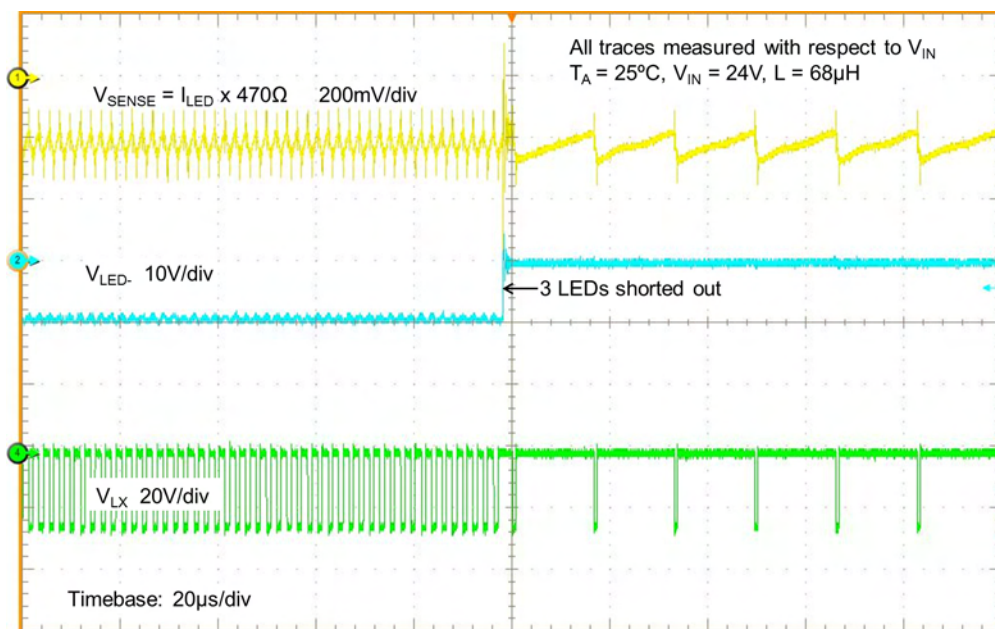
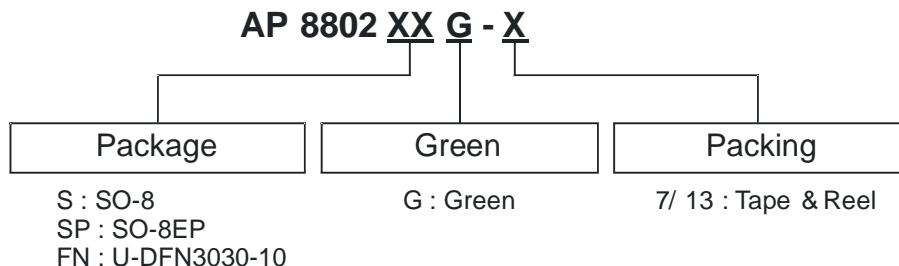


Figure. 24 Switching Characteristics (normal open to short LED chain)

## Ordering Information

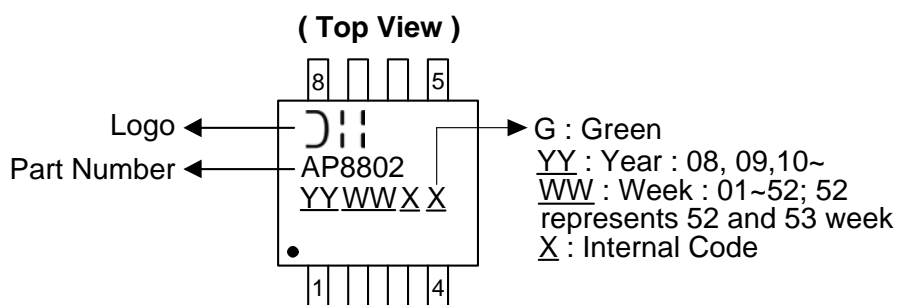


Device	Package Code	Packaging (Note 11)	7"/13" Tape and Reel	
			Quantity	Part Number Suffix
AP8802SG-13	S	SO-8	2500/Tape & Reel	-13
AP8802SPG-13	SP	SO-8EP	2500/Tape & Reel	-13
AP8802FNG-7	FN	U-DFN3030-10	3000/Tape & Reel	-7

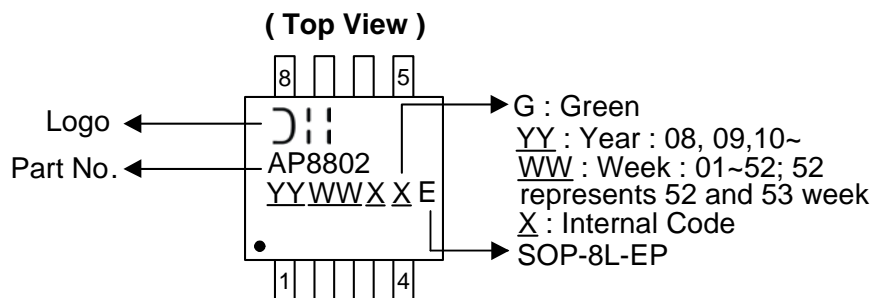
Notes: 11. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

## Marking Information

### (1) SO-8



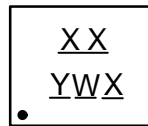
### (2) SO-8EP



## Marking Information (cont.)

### (3) U-DFN3030-10

#### ( Top View )



XX : Identification Code

Y : Year : 0~9

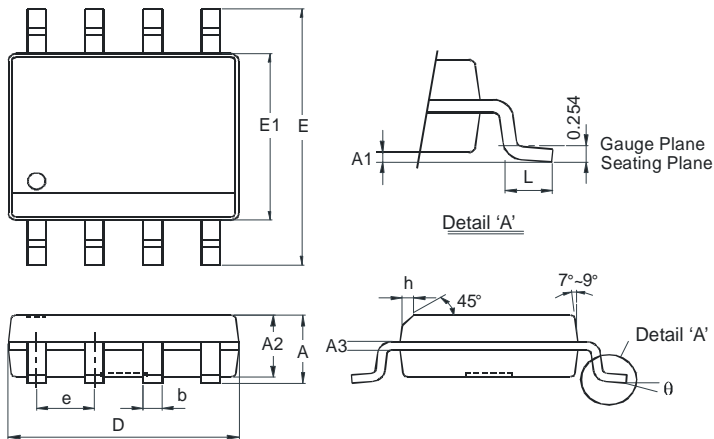
W : Week : A~Z : 1~26 week;  
a~z : 27~52 week; z represents  
52 and 53 week

X : A~Z : Green

Part Number	Package	Identification Code
AP8802FNG-7	U-DFN3030-10	A5

## Package Outline Dimensions (All Dimensions in mm)

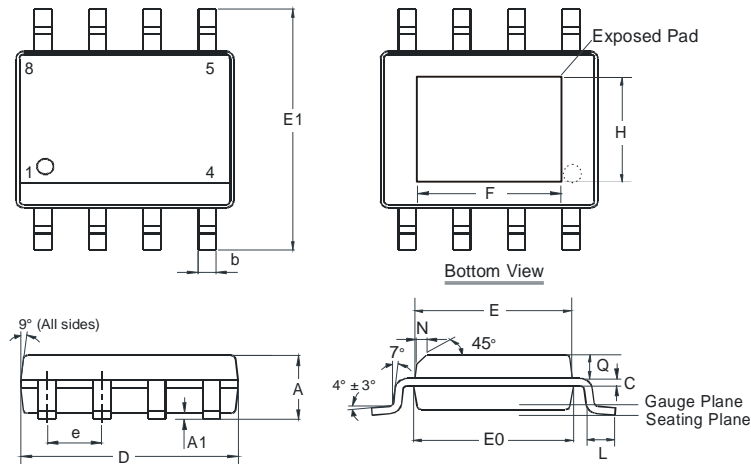
### (1) Package Type: SO-8



SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Dimensions in mm		

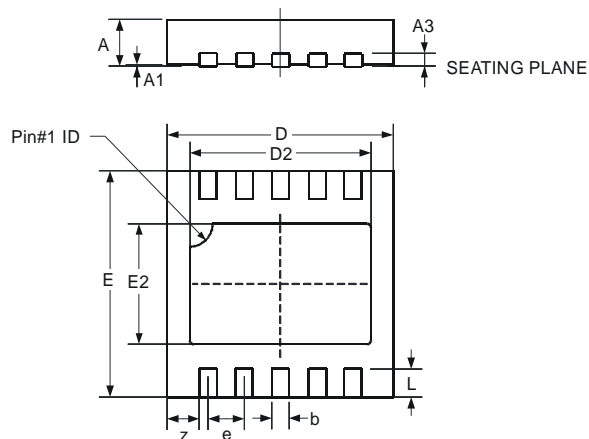
**Package Outline Dimensions (cont.) (All Dimensions in mm)**

**(2) Package Type: SO-8EP**



SO-8EP (SOP-8L-EP)			
Dim	Min	Max	Typ
A	1.40	1.50	1.45
A1	0.00	0.13	-
b	0.30	0.50	0.40
C	0.15	0.25	0.20
D	4.85	4.95	4.90
E	3.80	3.90	3.85
E0	3.85	3.95	3.90
E1	5.90	6.10	6.00
e	-	-	1.27
F	2.75	3.35	3.05
H	2.11	2.71	2.41
L	0.62	0.82	0.72
N	-	-	0.35
Q	0.60	0.70	0.65
All Dimensions in mm			

**(3) Package Type: U-DFN3030-10**

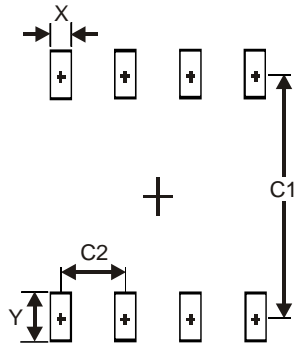


U-DFN3030-10			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	—	—	0.15
b	0.20	0.30	0.25
D	2.90	3.10	3.00
D2	2.30	2.50	2.40
e	—	—	0.50
E	2.90	3.10	3.00
E2	1.50	1.70	1.60
L	0.25	0.55	0.40
z	—	—	0.375
All Dimensions in mm			



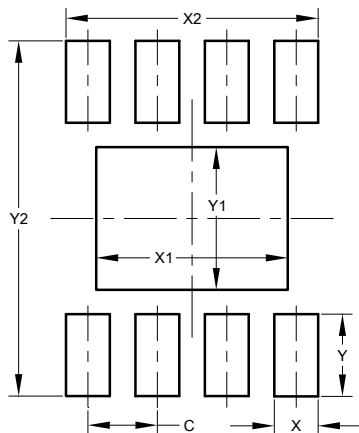
## Suggested Pad Layout

### (1) Package Type: SO-8



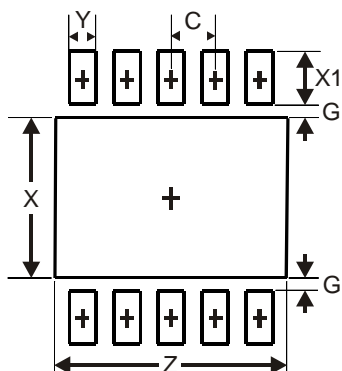
Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

### (2) Package Type: SO-8EP



Dimensions	Value (in mm)
C	1.270
X	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500

### (3) Package Type: U-DFN3030-10



Dimensions	Value (in mm)
Z	2.60
G	0.15
X	1.80
X1	0.60
Y	0.30
C	0.50

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